

ITEM :

CRYSTAL OSCILLATOR

TYPE :

DSO221SHF

NOMINAL FREQUENCY :

24.000MHz

SPEC No. :

1XSF024000EHC

Please acknowledge receipt of this specification by signing and returning a copy to us.

RECEIPT		
DATE		
RECEIVED	(signature) (name)	



- 1. Device Name
- 2. Type Name
- Name DSO221SHF
- 3. Nominal Frequency 24.000MHz

4. Absolute Maximum Ratings

Item	Symbol	Value	Unit
Vcc terminal voltage	V _{CC}	-0.6~+6.0	V
Input terminal voltage	V _{IN}	-0.6~ Vcc +0.6	V
Output terminal voltage	V _{OUT}	-0.6~ Vcc +0.6	V
Output terminal current	I _{OUT}	10	mA
Storage temp. range	T stg	-40~+85	°C

SPXO (Output Load Condition C-MOS)

5. Electric Specifications

Itom	Symbol	Value			Linit	Condition	
item	Symbol	min.	typ.	max.	Unit	V _{CC}	Temp.
Total Frequency tolerance	f_ _{tol}	-50	-	+50	ppm	+1.8±0.2V	-10~+70°C
Operating temp. range	T_use	-10	+25	+70	°C		-
Supply voltage	V _{CC}	+1.6	+1.8	+2.0	V	-	-10~+70°C
Current consumption(No Load) (#1 Pin:Open or "H")	I _{CC}	-	-	2.8	mA		
Standby Current (#1 Pin :"L")	I_std	-	-	0.01	mA		
Symmetry (Duty Cycle)	SYM	45	50	55	%	I	
Low level output voltage	V _{OL}	-	-	Vccx0.1	V		
High level output voltage	V _{OH}	Vccx0.9	-	-	V	I	
Rise & Fall time	tr / tf	-	-	6	ns	+1.8V	+25±3°C
Output Load	L_ _{CMOS}	-	-	15	pF		
Low level input current	IIL	-	-	-0.01	mA		
High level input current	IIH	-	-	0.01	mA		
Low level input voltage	V _{IL}	-	-	Vccx0.2	V		
High level input voltage	V _{IH}	Vccx0.8	-	-	V		
Output disable time	tPLZ	-	-	150	ns		
Output enable time	tPZL	-	-	1	ms		

Measurement circuit and output wave form is refer to Fig.1. and Fig.2.

				2:Style 010Vor 1
2016/05/17				1 / 10
DATE		SPEC. No.	REV.	PAGE
DSO221SHF TYPE	CRYSTAL OSCILLATOR SPECIFICATION	REMARK		

DAISHINKU CORP.

DM-Z0002:Style-010Ver.1



6. Dimensions

$\begin{array}{c} 2.5 \\ \# 4 \\ 0 \\ 1 \\ \# 1 \\ \# 1 \\ \# 2$	Pin Connections Pin No. Connection #1 OE(Output Enable) #2 GND #3 Output #4 Vcc Tolerance: ±0.15 unit: mm		
#4 0.73 #1 Index #1 Index #3 4			
Type code(1) should be printed as follows by producing Type Marking DSO221SHF HF Nominal Frequency (2) and Logo(3) should be printed a Made in JAPAN → Spec.No. : 1XSF024000	g district as follows by producing district EHC Frequency : 24.0	Logo : D	
Manufacturing lot No.(4)(Year and Week):3 nur Year : The last digit of the year Week : We gave the sequence of week nu There are starting from 1st of during the nine weeks. The week means are from Sunc Example 2016/5/19 :	nbers as follows mbers 01(first week) for production date. Jan. However,add '0' figure to the first week lay to Saturday. 6 21 year week		
TITLE DS0221SHF TYPE CRYSTAL OSCILLATOR SPECIFICATION DATE	REMARK SPEC. No. 1XSF024000EHC	REV.	PAGE
2016/05/17			3 / 10
DAISHINKU	CORP.	DM-Z000	2:Style-010Ver.1

7. Mechanical Performance

7.1 Natural Drop

Drop 3 times from the height of 50cm onto min. 30mm thickness hard wooden board. The component shall satisfy requirement of the electrical characteristics.

7.2 Resistance impact

6ms/1000m/s² to X,Y and Z axes (6 directions), 3cycles. The component shall satisfy requirement of the electrical characteristics. No physical damage.

7.3 Vibration

Frequency 10 ~ 55Hz, Sine Wave full amplitude of 1.5mm to X, Y and Z axis, Duration of 2h to each axis. The component shall satisfy requirement of the electrical characteristics. No physical damage.

7.4 Sealing Tightness Leak Rate 1.0×10⁻⁹ Pa m³/s max. measured by Helium leak detector. And no bubble continued (1 time max.) in Fluorinert at +125± 5°C.

7.5 Solderability After applying ROSIN Flux, dipping in solder bath at +245± 5°C for 5s. Over 90% of terminal shall be covered by solder.

8. Environment Performance

8.1 Humidity Temperature +60± 2°C RH 90 ~ 95 %, Duration of 240h.

Back to the room temperature first, then in 24h, the component shall be checked. The component shall satisfy requirement of the electrical characteristics. No physical damage.

 8.2 Storage in Low Temperature Lower Operating temperature ± 3°C Duration of 240h.
 Back to the room temperature first, then in 24h, the component shall be checked.
 The component shall satisfy requirement of the electrical characteristics. No physical damage.

8.3 Storage in High Temperature Upper Operating temperature ± 2°C Duration of 240h. Back to the room temperature first, then in 24h, the component shall be checked. The component shall satisfy requirement of the electrical characteristics. No physical damage.

8.4 Temperature cycles

Lower Operating temperature ± 3°C (30 min) <-> Upper Operating temperature ± 2°C (30 min) 20 cycles. Back to the room temperature first, then in 24h, the component shall be checked. The component shall satisfy requirement of the electrical characteristics. No physical damage.

8.5 High Temperature Operation

Upper Operating temperature ± 2°C maximam V_{CC} Duration of 240h. Back to the room temperature first, then in 24h, the component shall be checked. The component shall satisfy requirement of the electrical characteristics. No physical damage.

(*) Upper Operating temperature: Case of +85°C max. -> +85°C (*) Lower Operating temperature: Case of -30°C max. -> -30°C

 8.6 Static Electricity
 Antistatic electrical intensity lebel Test Conditions
 Breakdown Voltage (MM) C=200pF, R=0Ω
 ±200 V

- (HBM) C=100pF, R=1.5kΩ ±2000 V
- Number of times : 3times max.

The component shall satisfy requirement of the electrical characteristics. No physical damage.

TITLE DS0221SHF TYPE CRYSTAL OSCILLATOR SPECIFICATION	REMARK		
DATE	SPEC. No. 1XSF024000EHC	REV.	PAGE
2016/05/17			4 / 10

9. Taping and Packing

9.2

9.1 Emboss Tape specifications



 Trailer
 Floduct Set part
 Leader

 Image: Cover tape
 Image: Cover tape

 Image: Cover tape
 Image: Cover tape

 #1 index
 Image: Cover tape

 Image: Cover tape
 Image: Cover tape

 Image: Cover tape

9.3 Taping Dimension

Loodor	Cover tape	The length of cover tape in the leader is more than 400mm including empty emboss area.
Leader	Emboss tape	After all products were packaged, must remain more than twenty pieces or 400mm empty area, which should be sealed by cover tape.
Trailer	Cover tape	The trailer area which are sealed by cover tape must remain more than 350mm.
Trailer	Emboss tape	

TITLE	REMARK		
DS0221SHF TYPE CRYSTAL OSCILLATOR SPECIFICATION			
DATE	SPEC. No.	REV.	PAGE
	1XSF024000EHC		
2016/05/17			5 / 10



DAISHINKU CORP.

- 9.6 Storage Temperature+40°C max. Humidity80% max.
- 9.7 Quantity on reel 2000pcs. / reel
- 9.8 Label



9.9 Shipping carton

Packed in a carton box. The following label on the side of carton box.



- 10. Supplement
 - 10.1 Reflow Soldering (Example)

Please stay with our proposed reflow condition and do then soldering 2 times max.



A:Pre Heat	120 s	
B:Heat	60 s	
C:Peak	10 s max	•
D:Pre Heat temp.	+160 ~ +180 °C	
E:Heat temp.	+220 °C	
F:Peak temp.	+260 °C	

10.2 Solder iron(Example) Bit temp.: +350°C max.,Time:5s max., Each terminal solder a 1 time max.

10.3 Land pattern layout (Example)



10.4 Mounting

This component is designed for automatic insertion.

However you are requested to do the trial with your insertion machine in order to be sure of proper operation and no damage of component.

Please pay attention to board warp which may damage the component and cause soldering process. Please mount so that the metalize side and other electrical conductivity structures (a main part lid is included) of the base side do not contact electrically.

2016/05/17			8 / 10	
DATE	SPEC. No. 1XSF024000EHC	REV.	PAGE	
TITLE DS0221SHF TYPE CRYSTAL OSCILLATOR SPECIFICATION	REMARK			

10.5 Cleaning

Cleaning liquid which corrodes Nickel shall not be used. It may cause the problem on the surface color marking etc. Ultrasonic cleaning is possible however you are requested to check on your board. Because we only checked as single unit.

10.6 Handling

This product is designed to withstand Drop and Vibration, however, the crystal blank might be broken. So if excess force is given, please check the characteristics before use. This product has C-MOS circuit inside. Please pay attention to latch-up, static-electricity as same handling as other C-MOS devices.

10.7 By-pass Capacitor

It has no by-pass capacitor integrated, we recommend you to use capacitor (like ceramic chip capacitor) 0.01μ F in-between Vcc and GND.

10.8 Storage

Please keep away from high temperature and high humidity, which may cause put solderbility. No direct Sunlight. No dew as well.

10.9 Thrust an ultrasonic cleaning

Because It use a small, thin crystal piece depending on a condition, the inside does resonance, and there is fear to cause the non-oscillation. When it's the worst, it may be destroyed. About the ultrasonic cleaning, it is use in the implementation of your company is in a state and confirming a thing without the influence in the appearance and a characteristic beforehand.

10.10 Point out supersonic wave welding

It can't recommend implementation by the supersonic wave welding and the processing so that the vibration excessive inside of the crystal oscillator propagates, and there is a threat that It cause characteristic deterioration and the non-oscillation.

10.11 RoHS Compliance

These Products do not contain the six substances restricted and prohibited on the restriction of the use of certain hazardous substances in electrical and electronic equipment.(DIRECTIVE 2011/65/EU OF THE EUROPIAN PARLIAMENT AND OF THE COUNCIL)

2016/05/17			9 / 10
DATE	SPEC. No. 1XSF024000EHC	REV.	PAGE
TITLE DS0221SHF TYPE CRYSTAL OSCILLATOR SPECIFICATION	REMARK		

Rev.No. Date Reason Contents Approved Checked Drawn 2016/05/17 -Initial Release S.Shigematsu Y.Kanazawa E.Kameda -

2016-0440 REVISION RECORD

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Standard Clock Oscillators category:

Click to view products by KDS manufacturer:

Other Similar products are found below :

601252 F335-25 F535L-33.333 F535L-50 ASV-20.000MHZ-LR-T ECS-2018-160-BN-TR MXO45HS-2C-66.6666MHZ SiT1602BI-22-33E-50.00000E SiT8209AI-32-33E-125.00000 SIT8918AA-11-33S-50.00000G SM4420TEV-40.0M-T1K SMA4306-TL-H F335-24 F335-40 F535L-10 F535L-12 F535L-16 F535L-24 F535L-27 F535L-48 PE7744DW-100.0M ASF1-3.686MHZ-N-K-S ASV-4.000MHZ-LCS-T XLH735025.000JU418 XLP725125.000JU618 XO57CTECNA3M6864 ECS-2100A-147.4 601251 EP16E7E2H26.000MTR SiT8503AI-18-33E-0.200000X SIT8918AA-11-33S-16.000000G SIT9122AI2C233E300.000000X XO37CTECNA20M XO3003 9120AC-2D2-33E212.500000 9102AI-243N25E100.00000 8208AC-82-18E-25.00000 ASDK2-32.768KHZ-LR-T3 8008AI-72-XXE-24.545454E 8004AC-13-33E-133.33000X AS-4.9152-16-SMD-TR ASFL1-48.000MHZ-LC-T 632L3I004M00000 SIT8920AM-31-33E-25.0000 DSC1028DI2-019.2000 9121AC-2C3-25E100.00000 9102AI-233N33E100.00000X 9102AI-233N25E200.00000 9102AI-232H25S125.00000 9102AI-133N25E200.00000